# onsemi

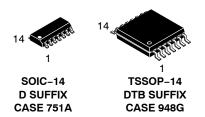
# Single Supply Quad Operational Amplifiers

# LM324, LM324A, LM324E, LM224, LM2902, LM2902E, LM2902V, NCV2902

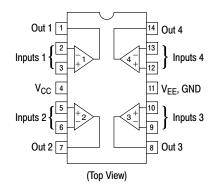
The LM324 series are low-cost, quad operational amplifiers with true differential inputs. They have several distinct advantages over standard operational amplifier types in single supply applications. The quad amplifier can operate at supply voltages as low as 3.0 V or as high as 32 V with quiescent currents about one-fifth of those associated with the MC1741 (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

#### Features

- Short Circuited Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 32 V
- Low Input Bias Currents: 100 nA Maximum (LM324A)
- Four Amplifiers Per Package
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Industry Standard Pinouts
- ESD Clamps on the Inputs Increase Ruggedness without Affecting Device Operation
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant







#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 11 of this data sheet.

#### **MAXIMUM RATINGS** ( $T_A = +25^{\circ}C$ , unless otherwise noted.)

Rating		Symbol	Value	Unit
Power Supply Voltages Single Supply Split Supplies		V <sub>CC</sub> V <sub>CC</sub> , V <sub>EE</sub>	32 ±16	Vdc
Input Differential Voltage Range (Note 1)		V <sub>IDR</sub>	±32	Vdc
Input Common Mode Voltage Range		V <sub>ICR</sub>	-0.3 to 32	Vdc
Output Short Circuit Duration		t <sub>SC</sub>	Continuous	
Junction Temperature		TJ	150	°C
Thermal Resistance, Junction-to-Air (Note 2)	Case 646 Case 751A Case 948G	$R_{ heta JA}$	118 156 190	°C/W
Storage Temperature Range		T <sub>stg</sub>	-65 to +150	°C
	LM224 LM324A, LM324E LM2902, LM2902E	T <sub>A</sub>	−25 to +85 0 to +70 −40 to +105	°C
LM2902V,	NCV2902 (Note 3)		-40 to +125	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Split Power Supplies.

2. All R<sub>0JA</sub> measurements made on evaluation board with 1 oz. copper traces of minimum pad size. All device outputs were active.

3. NCV2902 is qualified for automitive use.

#### ESD RATINGS

Rating	НВМ	ММ	Unit
ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM)			
NCV2902 (Note 3)	2000	200	V
LM324E, LM2902E	2000	200	V
LM324DG/DR2G, LM2902DG/DR2G	200	100	V
All Other Devices	2000	200	V

		Image: Line system      Line system <thline system<="" th=""></thline>						10000									
				-			-					,	-				
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Мах	Min	Тур	Max	Min	Тур	Мах	Min	Тур	Мах	Unit
Input Offset Voltage $ \begin{aligned} V_{CC} &= 5.0 \text{ V to } 30 \text{ V} \\ V_{ICR} &= 0 \text{ V to} \\ V_{CC} &- 1.7 \text{ V}, \\ V_{O} &= 1.4 \text{ V}, \text{ R}_{S} &= 0 \ \Omega \end{aligned} $	V <sub>IO</sub>																mV
$T_A = 25^{\circ}C$		-	2.0	5.0	-	2.0	3.0	-	2.0	7.0	-	2.0	7.0	-	2.0	7.0	
$T_A = T_{high}$ (Note 4)		_	-	7.0 7.0	-	-	5.0 5.0	-	-	9.0 9.0	-	-	10 10	-	-	13 10	
T <sub>A</sub> = T <sub>low</sub> (Note 4) Average Temperature Coefficient of Input Offset Voltage	$\Delta V_{IO} / \Delta T$	-	7.0	-	-	7.0	30	-	7.0	-	-	7.0	-	-	7.0	-	μV/°C
T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub> (Notes 4 and 6)																	
Input Offset Current $T_A = T_{high}$ to $T_{low}$ (Note 4)	Ι <sub>ΙΟ</sub>		3.0 -	30 100	-	5.0 -	30 75	-	5.0 -	50 150	-	5.0 -	50 200	-	5.0 -	50 200	nA
Average Temperature Coefficient of Input Offset Current $T_A = T_{high}$ to $T_{low}$	$\Delta I_{IO} / \Delta T$	I	10	_	_	10	300	_	10	-	_	10	_	_	10	_	pA/°C
(Notes 4 and 6)																	
Input Bias Current T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub> (Note 4)	I <sub>IB</sub>	-	-90 -	-150 -300	-	-45 -	-100 -200	-	-90 -	-250 -500	-	-90 -	-250 -500	_	-90 -	-250 -500	nA
Input Common Mode Voltage Range (Note 5) V <sub>CC</sub> = 30 V	V <sub>ICR</sub>																V
$T_A = +25^{\circ}C$		0	-	28.3	0	-	28.3	0	-	28.3	0	-	28.3	0	-	28.3	
T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub> (Note 4)		0	-	28	0	_	28	0	_	28	0	-	28	0	_	28	
Differential Input Voltage Range	V <sub>IDR</sub>	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	-	-	V <sub>CC</sub>	V
Large Signal Open Loop Voltage Gain $R_L = 2.0 k\Omega$ , $V_{CC} = 15 V$ , for Large $V_O$ Swing	A <sub>VOL</sub>	50	100	-	25	100	-	25	100	-	25	100	-	25	100	-	V/mV
$T_A = T_{high}$ to $T_{low}$ (Note 4)		25	-	-	15	-	-	15	-	-	15	-	-	15	-	-	
$\begin{array}{l} \mbox{Channel Separation} \\ \mbox{10 kHz} \leq f \leq 20 \mbox{ kHz}, \\ \mbox{Input Referenced} \end{array}$	CS	_	-120	-	-	-120	-	-	-120	-	_	-120	-	-	-120	-	dB
$\begin{array}{l} \mbox{Common Mode} \\ \mbox{Rejection,} \\ \mbox{R}_S \leq 10 \ \mbox{k}\Omega \end{array}$	CMR	70	85	-	65	70	-	65	70	-	50	70	-	50	70	-	dB
Power Supply Rejection	PSR	65	100	-	65	100	-	65	100	-	50	100	-	50	100	-	dB

#### **ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 5.0 \text{ V}$ , $V_{FF} = \text{GND}$ , $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.)

4. LM224: T<sub>Iow</sub> = -25°C, T<sub>high</sub> = +85°C LM324/LM324A/LM324E: T<sub>Iow</sub> = 0°C, T<sub>high</sub> = +70°C LM2902/LM2902E: T<sub>Iow</sub> = -40°C, T<sub>high</sub> = +105°C LM2902V & NCV2902: T<sub>Iow</sub> = -40°C, T<sub>high</sub> = +125°C NCV2902 is qualified for automotive use.

 The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V<sub>CC</sub> –1.7 V, but either or both inputs can go to +32 V without damage, independent of the magnitude of V<sub>CC</sub>.

6. Guaranteed by design.

ELECTRICAL CHA			LM224 LM324A L				324, LM			902, LM	2902E	LM29	02V/NC	V2902			
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Output Voltage – High Limit V <sub>CC</sub> = 5.0 V, R <sub>L</sub> =	V <sub>OH</sub>	3.3	3.5	_	3.3	3.5	_	3.3	3.5	_	3.3	3.5	_	3.3	3.5	_	V
$\begin{array}{l} 2.0 \text{ k}\Omega,  \text{T}_{\text{A}} = 25^{\circ}\text{C} \\ \text{V}_{\text{CC}} = 30 \text{ V} \\ \text{R}_{\text{L}} = 2.0  \text{k}\Omega \\ (\text{T}_{\text{A}} = \text{T}_{\text{high to}}  \text{T}_{\text{low}}) \end{array}$		26	-	-	26	-	-	26	-	-	26	-	-	26	-	-	
$      (Note 7) \\ V_{CC} = 30 V \\ R_L = 10 k\Omega \\ (T_A = T_{high to} T_{low}) \\ (Note 7) $		27	28	-	27	28	-	27	28	-	27	28	-	27	28	-	
$\begin{array}{l} Output \mbox{ Voltage } - \\ Low \mbox{ Limit,} \\ V_{CC} = 5.0 \mbox{ V,} \\ R_L = 10 \mbox{ k}\Omega, \\ T_A = T_{high} \mbox{ to } T_{low} \\ (Note \mbox{ 7}) \end{array}$	V <sub>OL</sub>	-	5.0	20	-	5.0	20	-	5.0	20	-	5.0	100	-	5.0	100	mV
Output Source Current ( $V_{ID} = +1.0 V$ , $V_{CC} = 15 V$ )	I <sub>O +</sub>																mA
T <sub>A</sub> = 25°C T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub> (Note 7)		20 10	40 20	-	20 10	40 20	-	20 10	40 20	-	20 10	40 20	-	20 10	40 20	-	
Output Sink Current $(V_{ID} = -1.0 V,$ $V_{CC} = 15 V)$ $T_A = 25^{\circ}C$	I <sub>O –</sub>	10	20	-	10	20	-	10	20	-	10	20	-	10	20	-	mA
$T_A = T_{high}$ to $T_{low}$ (Note 7)		5.0	8.0	-	5.0	8.0	-	5.0	8.0	_	5.0	8.0	_	5.0	8.0	-	
$(V_{ID} = -1.0 \text{ V},$ $V_O = 200 \text{ mV},$ $T_A = 25^{\circ}\text{C})$		12	50	-	12	50	-	12	50	-	-	-	-	-	-	-	μΑ
Output Short Circuit to Ground (Note 8)	I <sub>SC</sub>	_	40	60	_	40	60	-	40	60	_	40	60	_	40	60	mA
Power Supply Current (T <sub>A</sub> = T <sub>high</sub> to T <sub>low</sub> ) (Note 7)	I <sub>CC</sub>																mA
$V_{CC} = 30 V$ $V_{O} = 0 V, R_{L} = \infty$		-	-	3.0	-	1.4	3.0	-	-	3.0	-	-	3.0	-	-	3.0	
$V_{CC} = 5.0 \text{ V},$ $V_{O} = 0 \text{ V}, \text{ R}_{L} = \infty$		-	-	1.2	-	0.7	1.2	-	-	1.2	-	-	1.2	-	-	1.2	

ELECTRICAL CHARACTERISTICS	$(V_{CC} = 5.0 \text{ V}, V_{FF} = \text{GND}, T_{\Delta} = 25^{\circ}\text{C}, \text{ unless otherwise noted}.)$
	$V_{CC} = 5.0$ V. VEE = GIND. $I_{\Delta} = 25$ C. UHESS UHERWISE HULEU.

7. LM224:  $T_{Iow} = -25^{\circ}C$ ,  $T_{high} = +85^{\circ}C$ LM324/LM324A/LM324E:  $T_{Iow} = 0^{\circ}C$ ,  $T_{high} = +70^{\circ}C$ LM2902/LM2902E:  $T_{Iow} = -40^{\circ}C$ ,  $T_{high} = +105^{\circ}C$ LM2902V & NCV2902:  $T_{Iow} = -40^{\circ}C$ ,  $T_{high} = +125^{\circ}C$ NCV2902 is qualified for automotive use.

8. The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V<sub>CC</sub> -1.7 V, but either or both inputs can go to +32 V without damage, independent of the magnitude of  $V_{CC}$ .

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

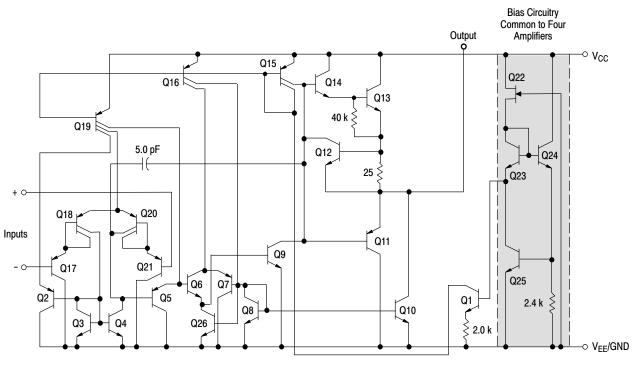
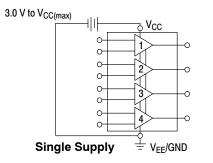


Figure 1. Representative Circuit Diagram (One–Fourth of Circuit Shown)

#### **CIRCUIT DESCRIPTION**

The LM324 series is made using four internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q20 and Q18 with input buffer transistors Q21 and Q17 and the differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q20 and Q18. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.



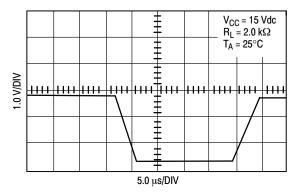
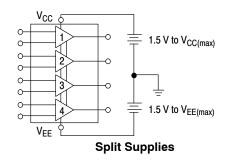


Figure 2. Large Signal Voltage Follower Response

Each amplifier is biased from an internal-voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.





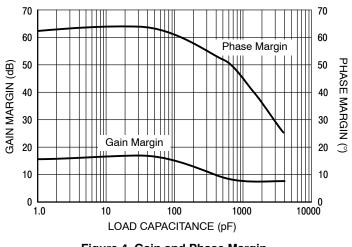
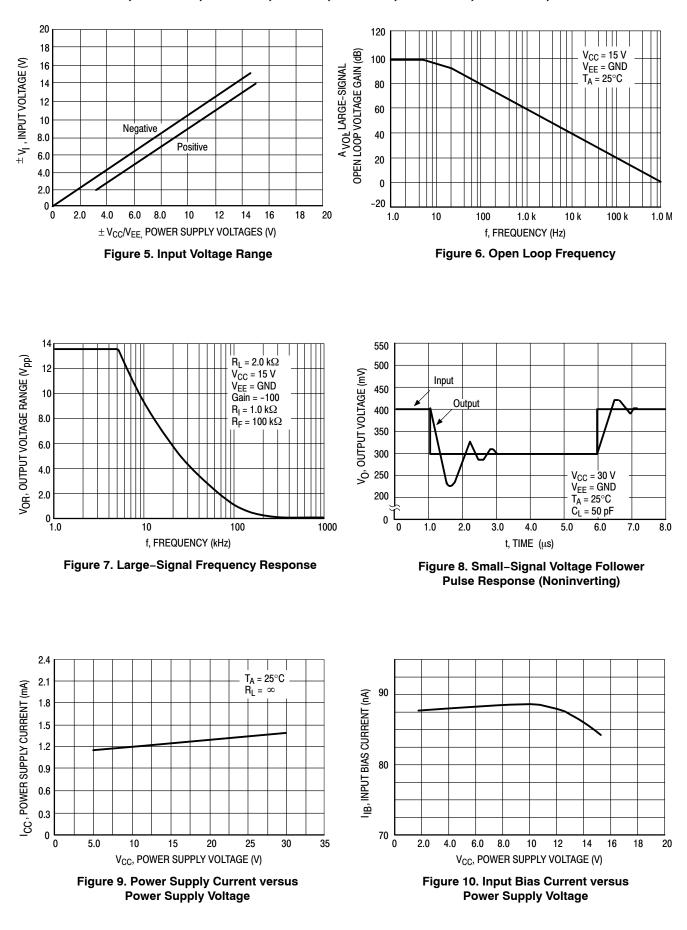


Figure 4. Gain and Phase Margin

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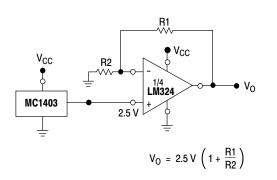


Figure 11. Voltage Reference

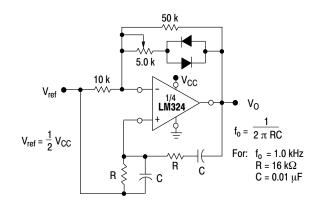


Figure 12. Wien Bridge Oscillator

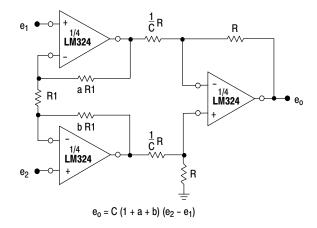


Figure 13. High Impedance Differential Amplifier

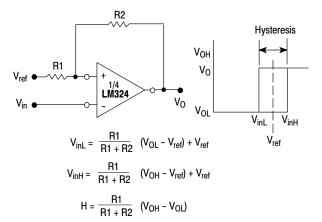


Figure 14. Comparator with Hysteresis

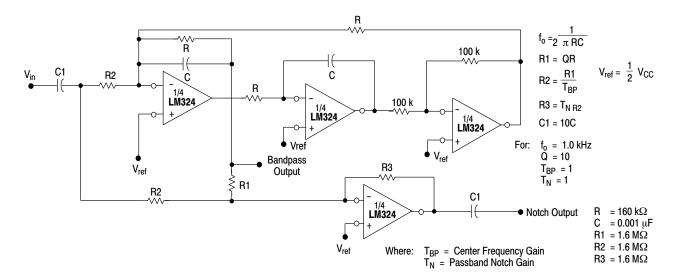


Figure 15. Bi-Quad Filter

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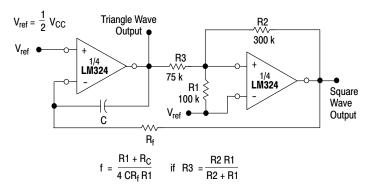
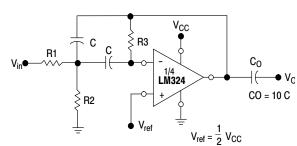


Figure 16. Function Generator





Given:  $f_0$  = center frequency A( $f_0$ ) = gain at center frequency

Choose value fo, C

Then: R3 = 
$$\frac{Q}{\pi f_0 C}$$
  
R1 =  $\frac{R3}{2 A(f_0)}$   
R2 =  $\frac{R1 R3}{4Q^2 R1 - R3}$ 

For less than 10% error from operational amplifier,  $\frac{Q_0 f_0}{BW} < 0.1$ 

where  $f_{0}\xspace$  and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

#### **ORDERING INFORMATION**

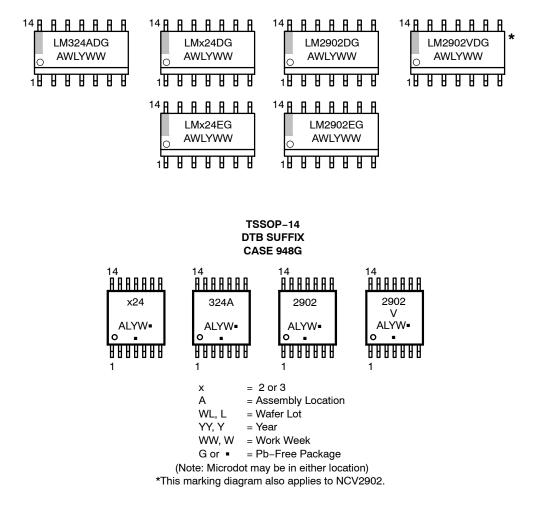
Device	Operating Temperature Range	Package	Shipping <sup>†</sup>	
LM224DR2G	0500 10 0500	SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM224DTBR2G	-25°C to +85°C	TSSOP-14 (Pb-Free)	2500/Tape & Reel	
LM324DR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM324EDR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM324DTBR2G	0°C to +70°C	TSSOP-14 (Pb-Free)	2500/Tape & Reel	
LM324ADR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM324ADTBR2G		TSSOP-14 (Pb-Free)	2500/Tape & Reel	
LM2902DR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM2902EDR2G	−40°C to +105°C	SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM2902DTBR2G		TSSOP-14 (Pb-Free)	2500/Tape & Reel	
LM2902VDR2G		SOIC-14 (Pb-Free)	2500/Tape & Reel	
LM2902VDTBR2G		TSSOP-14 (Pb-Free)	2500/Tape & Reel	
NCV2902DR2G*	-40°C to +125°C	SOIC-14 (Pb-Free)		
NCV2902DTBR2G*		TSSOP-14 (Pb-Free)	2500/Tape & Reel	

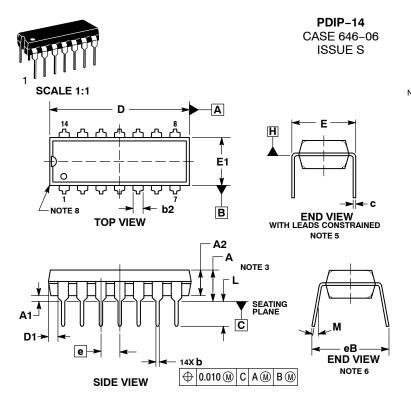
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. \*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

#### MARKING DIAGRAMS

#### SOIC-14 D SUFFIX CASE 751A





**STYLES ON PAGE 2** 

#### **ON Semiconductor**

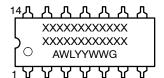


#### DATE 22 APR 2015

- NOTES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: INCHES.
  DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
  DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT DE VICE DA 10 INCH. NOT TO EXCEED 0.10 INCH. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM
- 5. PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- 6.
- DIMENSION & BIS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CODNEPS) 7.
- 8. CORNERS).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060	TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005		0.13	
Е	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54	BSC
eB		0.430		10.92
L	0.115	0.150	2.92	3.81
М		10°		10°

#### GENERIC **MARKING DIAGRAM\***



XXXXX = Specific Device Code

- = Assembly Location
- WL = Wafer Lot
- YY = Year

A

G

- ww = Work Week
  - = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

DOCUMENT NUMBER:	98ASB42428B	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED 0	
DESCRIPTION:	PDIP-14		PAGE 1 OF 2
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#### PDIP-14 CASE 646-06 ISSUE S

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STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. DRAIN 2. SOURCE 3. GATE 4. NO CONNECTION 5. GATE 6. SOURCE 7. DRAIN 8. DRAIN 9. SOURCE 10. GATE 11. NO CONNECTION 12. GATE 13. SOURCE 14. DRAIN
STYLE 5: PIN 1. GATE 2. DRAIN 3. SOURCE 4. NO CONNECTION 5. SOURCE 6. DRAIN 7. GATE 8. GATE 9. DRAIN 10. SOURCE 11. NO CONNECTION 12. SOURCE 13. DRAIN 14. GATE	STYLE 6: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 7: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 8: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STVLE 9: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE	STYLE 10: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 11: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 12: PIN 1. COMMON CATHODE 2. COMMON ANODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. COMMON ANODE 7. COMMON CATHODE 8. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE 14. ANODE/CATHODE

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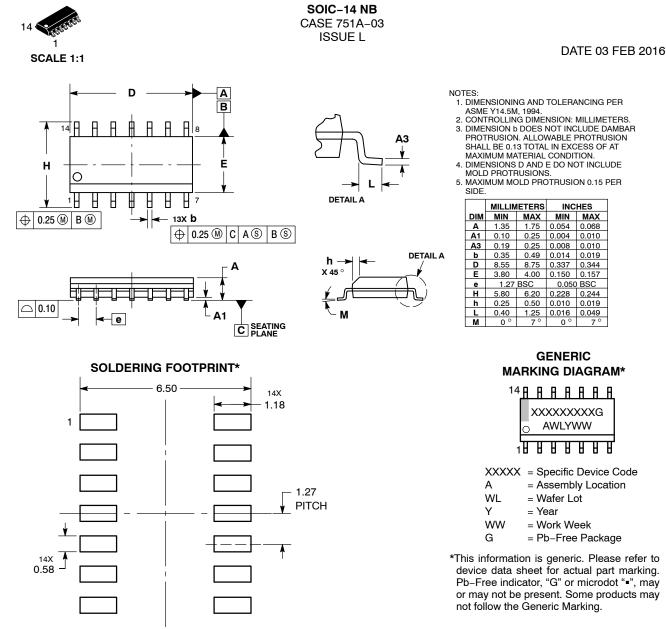
# DUSEM

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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#### DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5:	STYLE 6:	STYLE 7:	STYLE 8:
PIN 1. COMMON CATHODE	PIN 1. CATHODE	PIN 1. ANODE/CATHODE	PIN 1. COMMON CATHODE
2. ANODE/CATHODE	2. CATHODE	2. COMMON ANODE	2. ANODE/CATHODE
3. ANODE/CATHODE	3. CATHODE	3. COMMON CATHODE	3. ANODE/CATHODE
4. ANODE/CATHODE	4. CATHODE	4. ANODE/CATHODE	4. NO CONNECTION
5. ANODE/CATHODE	5. CATHODE	5. ANODE/CATHODE	5. ANODE/CATHODE
6. NO CONNECTION	6. CATHODE	6. ANODE/CATHODE	6. ANODE/CATHODE
7. COMMON ANODE	7. CATHODE	7. ANODE/CATHODE	7. COMMON ANODE
8. COMMON CATHODE	8. ANODE	8. ANODE/CATHODE	8. COMMON ANODE
9. ANODE/CATHODE	9. ANODE	10. ANODE/CATHODE	9. ANODE/CATHODE
10. ANODE/CATHODE	10. ANODE	11. COMMON CATHODE	10. ANODE/CATHODE
11. ANODE/CATHODE	11. ANODE	12. COMMON CATHODE	11. NO CONNECTION
12. ANODE/CATHODE	12. ANODE	13. ANODE/CATHODE	12. ANODE/CATHODE
13. NO CONNECTION	13. ANODE	14. ANODE/CATHODE	13. ANODE/CATHODE
14. COMMON ANODE	14. ANODE	14. ANODE/CATHODE	14. COMMON CATHODE

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